

Diode Ultra Fast



RoHS
Compliant



Features:

- High efficiency, low V_F
- High current capability
- High reliability
- High surge current capability
- For use in low voltage, high frequency inverter, free wheeling, and polarity protection application

Specifications:

Mechanical Data:

Cases	: Moulded plastic DO-41
Lead	: Pure tin plated, lead free, solderable per MIL-STD-202, Method 208 guaranteed
Polarity	: Colour band denotes cathode end
High temperature soldering guaranteed	: 260°C/10 seconds/0.375", (9.5mm) lead lengths at 5lbs., (2.3kg) tension
Weight	: 0.34g

Maximum Ratings and Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

Type Number	Symbol	HER108	Units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	1000	V
Maximum RMS Voltage	V_{RMS}	700	
Maximum DC Blocking Voltage	V_{DC}	1,000	
Maximum Average Forward Rectified Current 0.375" (9.5mm) Lead Length at $T_A = 55^\circ\text{C}$	$I_{(AV)}$	1	A
Peak Forward Surge Current, 8.3ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I_{FSM}	30	
Maximum Instantaneous Forward Voltage at 1A	V_F	1.7	V

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Type Number	Symbol	HER108	Units
Maximum DC Reverse Current at $T_A = 25^\circ\text{C}$ at Rated DC Blocking Voltage at $T_A = 125^\circ\text{C}$	I_R	5 150	μA μA
Maximum Reverse Recovery Time (Note 1)	T_{rr}	75	nS
Typical Junction Capacitance (Note 2)	C_j	20	pF
Typical Thermal Resistance	$R_{\theta JA}$	70	$^\circ\text{C/W}$
Operating Temperature Range	T_J	-65 to +150	$^\circ\text{C}$
Storage Temperature Range	T_{STG}		

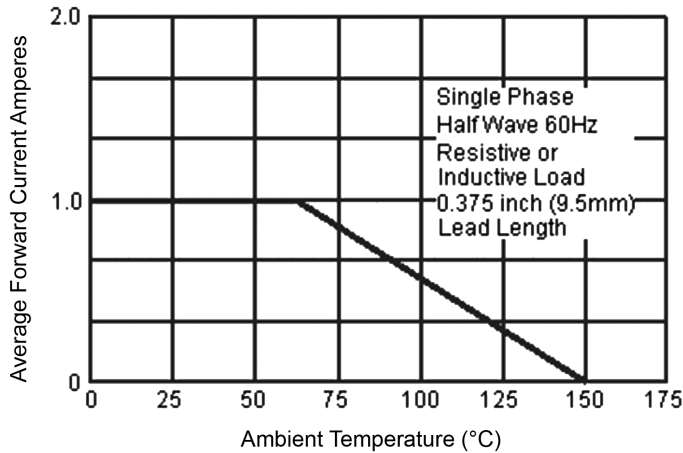
Note 1. Reverse Recovery Test Conditions: $I_F = 0.5\text{A}$, $I_R = 1.0\text{A}$, $I_{RR} = 0.25\text{A}$.

Note 2. Measured at 1MHz and Applied Reverse Voltage of 4V DC.

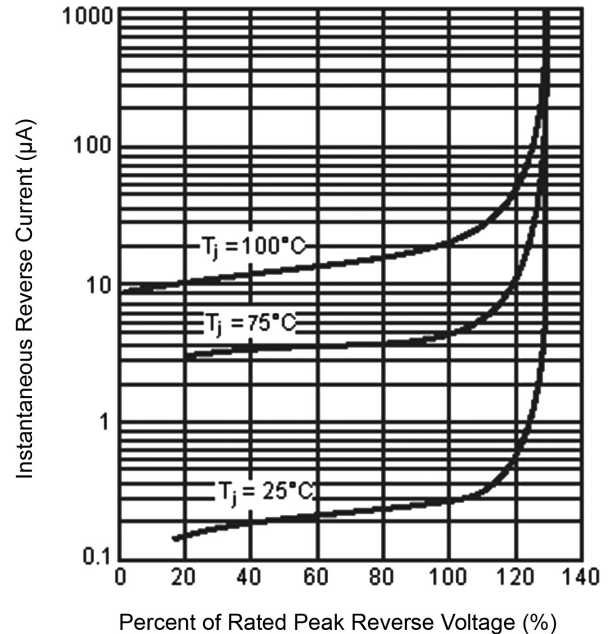
Note 3. Mount on Cu-Pad Size 5mm × 5mm on PCB.

Ratings and Characteristic Curves (HER108)

Maximum Forward Current Derating Curve



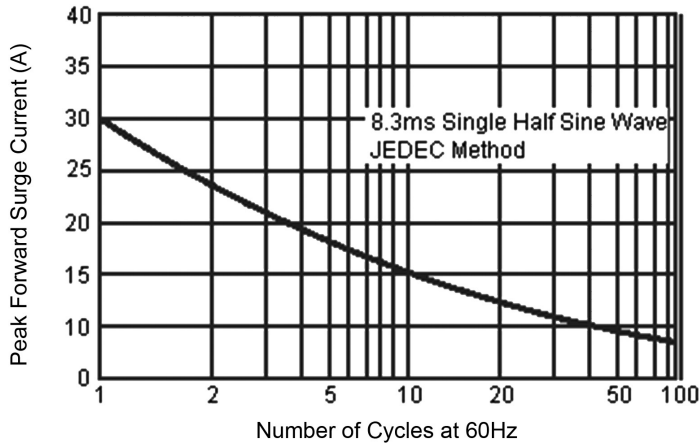
Typical Reverse Characteristics Per Leg



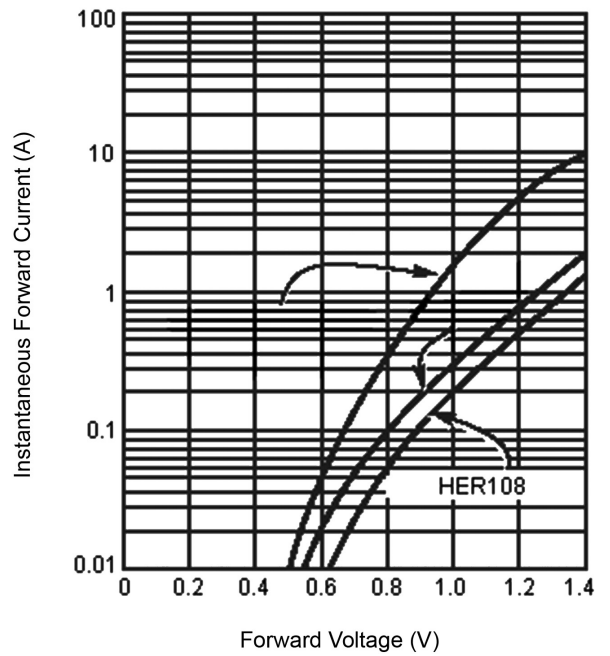
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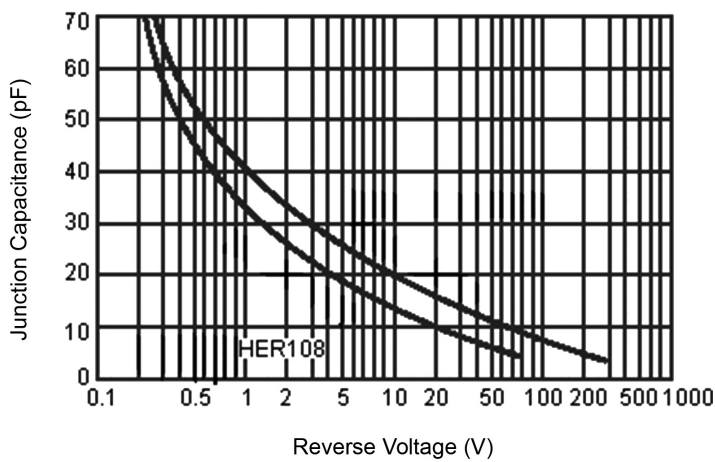
Maximum Non-Repetitive Forward Surge Current



Typical Forward Characteristics



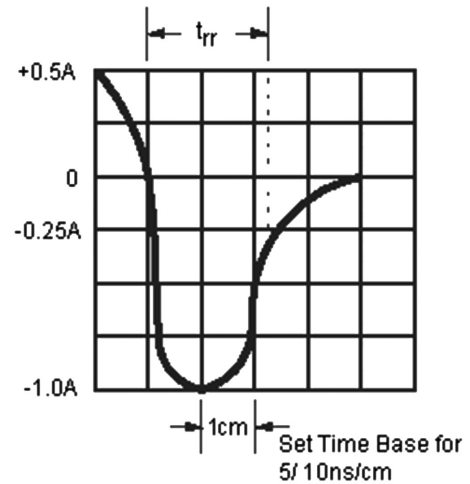
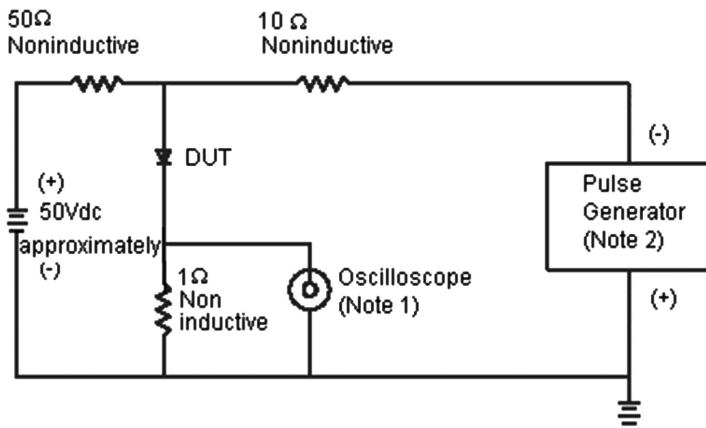
Typical Junction Capacitance



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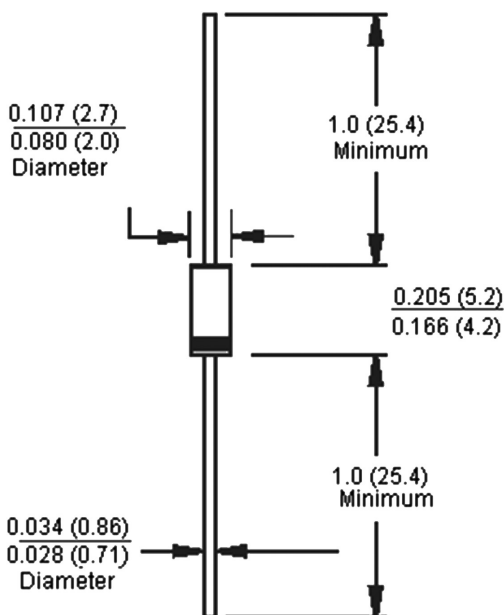
Reverse Recovery Time Characteristic and Test Circuit Diagram



Note: 1. Rise Time = 7ns Maximum. Input Impedance = 1MΩ 22pf

Note: 2. Rise Time = 10ns Maximum Source Impedance = 50Ω

DO-41



Dimensions : Inches (Millimetres)

Part Number Table

Description	Part Number
Diode, Ultra-Fast, 1A, 1,000V	HER108

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